

View Online at <https://aerobasegroup.com/nsn/5961-01-223-9424>

Inclosure Material:

Ceramic

Overall Length:

0.785 inches

Overall Height:

0.200 inches

Overall Width:

0.320 inches

Component Name And Quantity:

4 transistor

Mounting Method:

Terminal

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

1.9 watts small-signal input power, common-collector absolute all transistor

Transfer Ratio:

75.0 static forward current transfer ratio, common-emitter all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Test Data Document:

96214-2692212 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

14 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0